



1W005 THRU 1W10

SINGLE PHASE 1.0 AMP SILICON BRIDGE RECTIFIERS

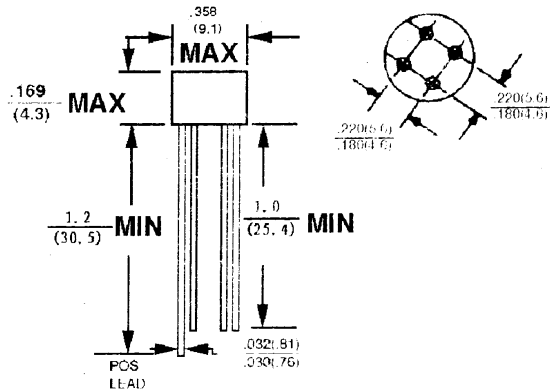


VOLTAGE RANGE
50 to 1000 Volts
CURRENT
1.0 Ampere

FEATURES

- * Ideal for printed circuit board
- * High Surge Current Capability
- * Reliable low cost construction technique results in inexpensive product

RB-15



Dimensions in inches and (millimeters)

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Rating at 25°C ambient temperature unless otherwise specified.
Single phase, half wave, 60 Hz, resistive or inductive load.
For capacitive load, derate current by 20%

TYPE NUMBER	SYMBOLS	1W005	1W01	1W02	1W04	1W06	1W08	1W10	UNITS
Maximum Recurrent Peak Reverse Voltage	V_{RRM}	50	100	200	400	600	800	1000	V
Maximum RMS Bridge Input Voltage	V_{RMS}	35	70	140	280	420	560	700	V
Maximum D. C Blocking Voltage	V_{DC}	50	100	200	400	600	800	1000	V
Maximum Average Forward Rectified Current @ $T_A = 60^\circ C$	$I_{F(AV)}$	1.0							A
Peak Forward Surge Current, 8.3 ms single half sine-wave superimposed on rated load (JEDEC method)	I_{FSM}	30							A
Maximum Forward Voltage Drop per element @ 1.0A	V_F	1.10							V
Maximum Reverse Current at Rated @ $T_A = 25^\circ C$ D. C. Blocking Voltage per element @ $T_A = 100^\circ C$	I_R	10 500							μA μA
Operating Temperature Range	T_J	- 55 to + 125							$^\circ C$
Storage Temperature Range	T_{STG}	- 55 to + 150							$^\circ C$

RATINGS AND CHARACTERISTIC CURVES (1W005 THRU 1W10)

FIG. 1-MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT - PER ELEMENT

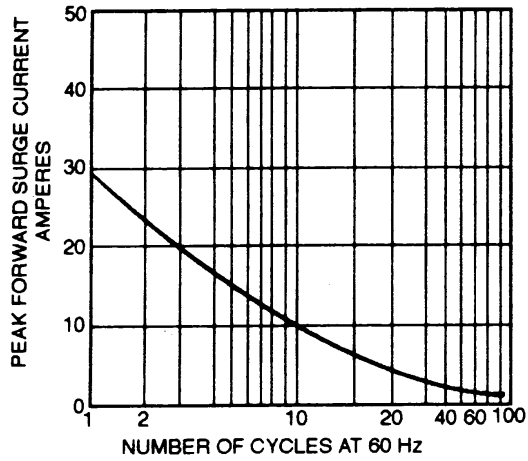


FIG. 2-TYPICAL FORWARD OUTPUT CURRENT DERATING CURVE

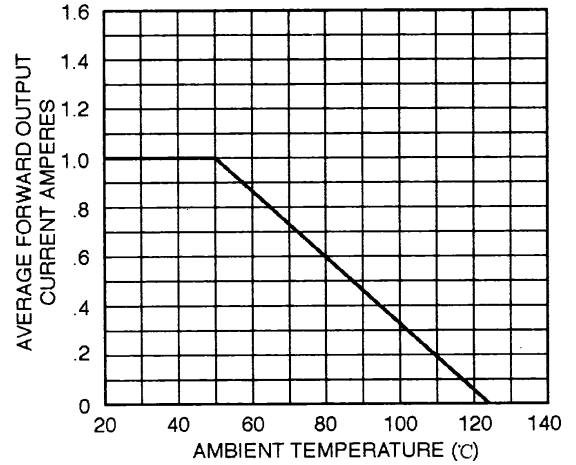


FIG. 3-TYPICAL FORWARD CHARACTERISTICS PER ELEMENT

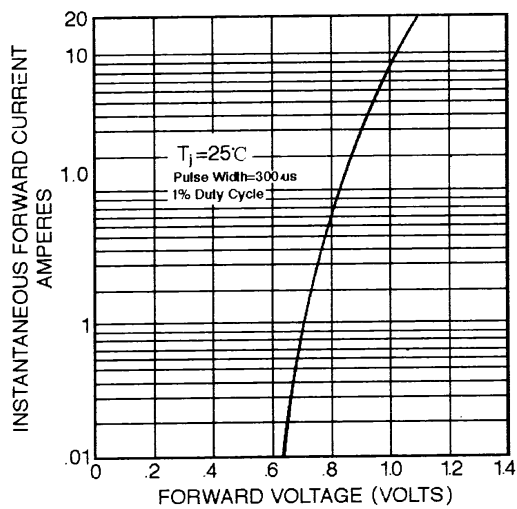


FIG. 4-TYPICAL REVERSE CHARACTERISTICS PER ELEMENT

